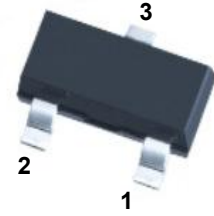


**Features**

- High Breakdown Voltage
- Low Saturation Voltage
- RoHS Compliant

- 1. Emitter
- 2. Base
- 3. Collector



SOT-23

**Applications**

- High Voltage Control Circuits

**Absolute Maximum Ratings**

(T<sub>A</sub>=25°C unless otherwise specified)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V <sub>CB0</sub>	500	V
Collector to Emitter Voltage	V <sub>CEO</sub>	400	V
Emitter to Base Voltage	V <sub>EBO</sub>	6.0	V
Collector Current	I <sub>C</sub>	300	mA
Collector Power Dissipation	P <sub>C</sub>	350	mW
Collector Power Dissipation	P <sub>C(TC=25°C)</sub>	1.5	W
Junction Temperature	T <sub>J</sub>	-55 to +150	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	°C

**Thermal Characteristics**

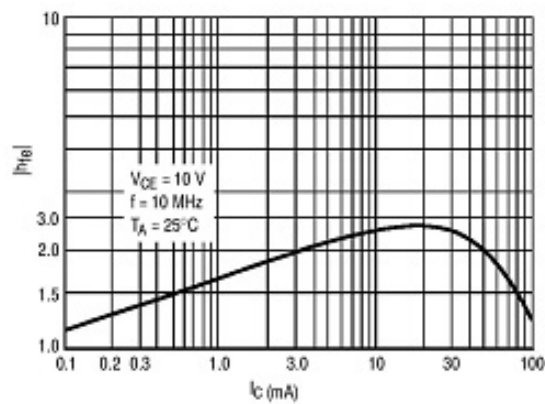
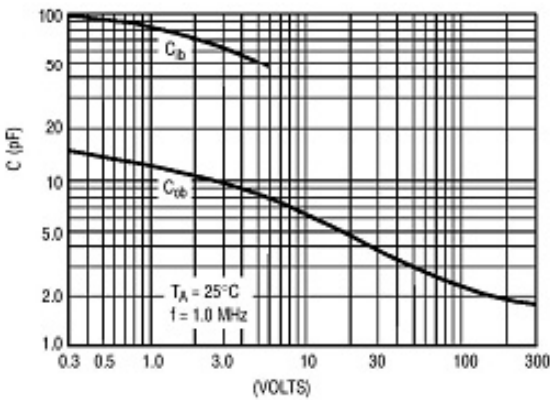
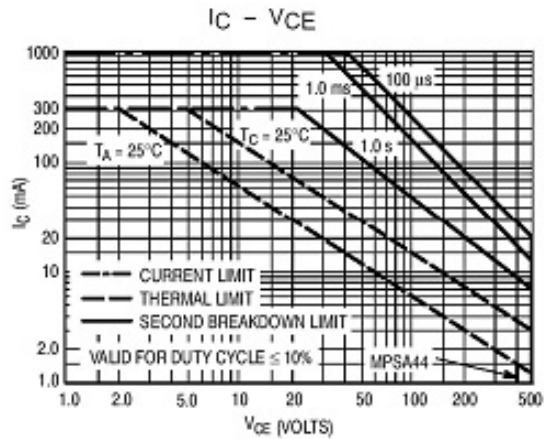
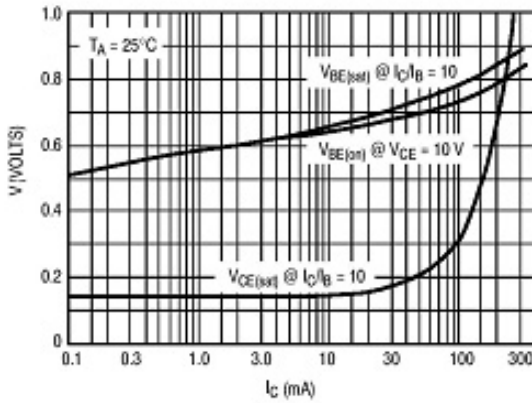
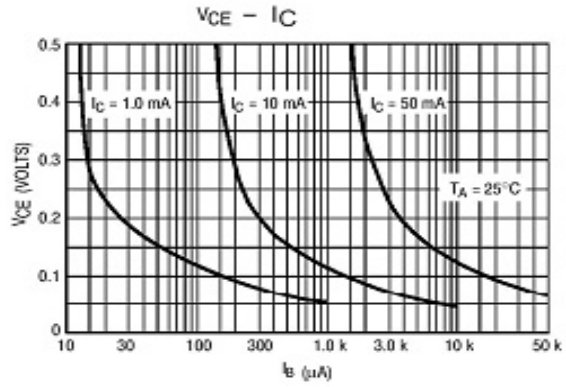
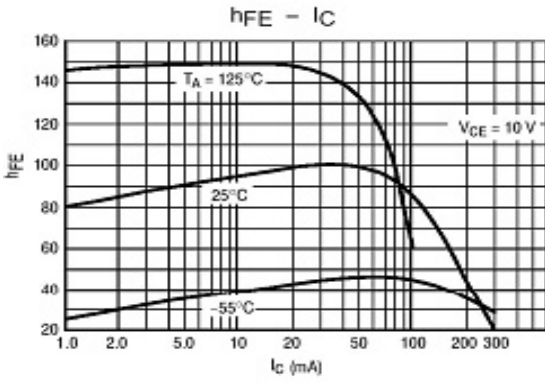
Parameter	Symbol	Typ.	Max.	Unit
Thermal Resistance Junction to Ambient	R <sub>θJA</sub>	---	357	°C/W

## Electrical Characteristics

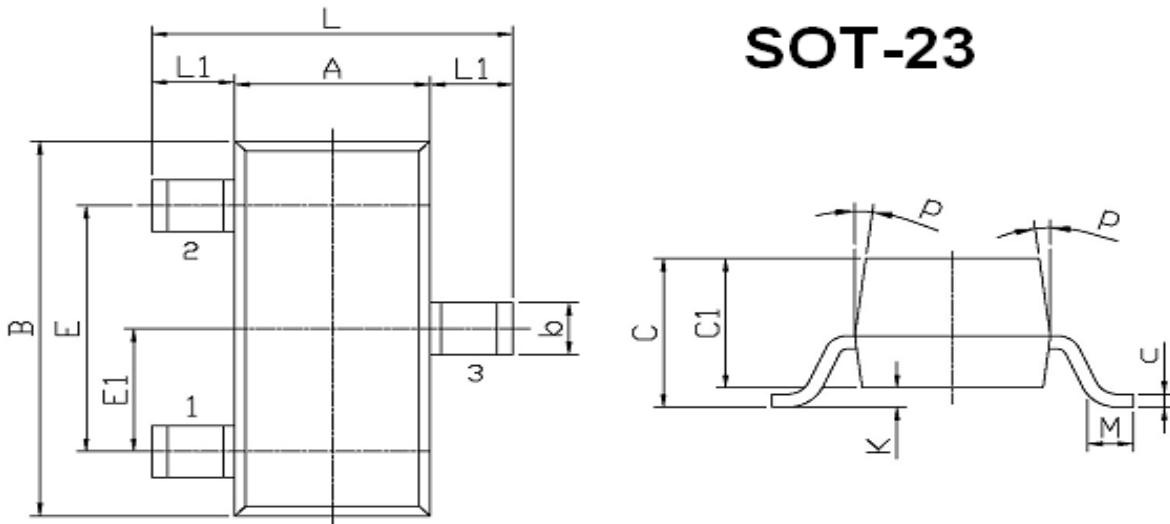
( $T_A=25^{\circ}\text{C}$  unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Emitter Breakdown Voltage	$V_{CEO}$	$I_C=100\mu\text{A}$ $I_E=0$	500	--	--	V
Collector to Base Breakdown Voltage	$V_{CBO}$	$I_C=1.0\text{mA}$ $I_B=0$	400	--	--	V
Emitter to Base Breakdown Voltage	$V_{EBO}$	$I_E=10\mu\text{A}$ $I_C=0$	6.0	--	--	V
Collector Cut-Off Current	$I_{CBO}$	$V_{CB}=400\text{V}$ $I_E=0$	--	--	0.1	$\mu\text{A}$
Collector Cut-Off Current	$I_{CEO}$	$V_{CE}=400\text{V}$ $V_{BE}=0$	--	--	0.5	$\mu\text{A}$
Emitter Cut-Off Current	$I_{EBO}$	$V_{CE}=4.0\text{V}$ $I_C=0$	--	--	0.1	$\mu\text{A}$
Forward Current Transfer Ratio(1)	$h_{FE(1)}$	$V_{CE}=10\text{V}$ $I_C=10\text{mA}$	50	--	200	
Forward Current Transfer Ratio(2)	$h_{FE(2)}$	$V_{CE}=10\text{V}$ $I_C=100\text{mA}$	40	--	--	
Forward Current Transfer Ratio(3)	$h_{FE(3)}$	$V_{CE}=10\text{V}$ $I_C=50\text{mA}$	45	--	--	
Forward Current Transfer Ratio(4)	$h_{FE(4)}$	$V_{CE}=10\text{V}$ $I_C=1.0\text{mA}$	40	--	--	
Collector-Emitter Saturation Voltage(1)	$V_{CE(sat)(1)}$	$I_C=1.0\text{mA}$ $I_B=0.1\text{mA}$	--	--	0.4	V
Collector-Emitter Saturation Voltage(2)	$V_{CE(sat)(2)}$	$I_C=10\text{mA}$ $I_B=1.0\text{mA}$	--	--	0.5	V
Collector-Emitter Saturation Voltage(3)	$V_{CE(sat)(3)}$	$I_C=50\text{mA}$ $I_B=5.0\text{mA}$	--	--	0.75	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=10\text{mA}$ $I_B=1.0\text{mA}$	--	--	0.75	V
Output Capacitance	$C_{ob}$	$V_{CB}=20\text{V}$ $f=1.0\text{MHz}$ $I_E=0$	--	--	7.0	pF

**Typical Characteristic Curves**



**Package Outline Dimensions**



Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters	
	Min	Max		Min	Max
L	2.2	2.7	C	1.30Max	
L1	0.45	0.65	C1	0.90	1.20
A	1.15	1.50	c	0.05	0.20
B	2.70	3.10	K	0	0.10
E	1.70	2.10	M	0.20MIN	
E1	0.85	1.05	P	7	
b	0.35	0.55			